

DECLARATION FOR PATENT APPLICATION Docket No. NECN 18.947

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

CHIP-TYPE SEMICONDUCTOR DEVICE

the specification of which

(check one) is attached hereto.

was filed on _____

as

Application Serial No. _____

and was amended on _____

(if applicable).

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by an amendment referred to above.

I acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, §1.56(a).

I hereby claim foreign priority benefits under Title 35, United States Code, §119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Prior Foreign Application(s)			Priority Claimed
2000-255126	Japan	25/8/2000 (Day/Month/Year Filed)	Yes <input checked="" type="radio"/> No <input type="radio"/>
(Number)	(Country)	(Day/Month/Year Filed)	Yes No
(Number)	(Country)	(Day/Month/Year Filed)	Yes No

I hereby claim the benefit under Title 35, United State Code, §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, §112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, §1.56(a) which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

(Application Serial No.)	(Filing Date)	(Status - patented, pending, abandoned)
(Application Serial No.)	(Filing Date)	(Status - patented, pending, abandoned)

I hereby appoint as my attorney and agent Aaron B. Karas, Reg. No. 18,923, Samson Helfgott, Reg. No. 23,072, Leonard Cooper Reg. No. 27,625 and Emma Shleifer, Reg. No. 29,734 to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith:

Address all correspondence to:

HELFGOTT & KARAS P.C.
60th Floor
Empire State Building
New York, New York 10118-0110
Telephone No. (212) 643-5000

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full name of sole or first inventor

GOFU IKEGAMI

Inventor's signature Gofu Ikegami

Date 21/08/2001

Residence Shiga, Japan

Citizenship Japanese

Post Office Address c/o NEC Kansai, Ltd., 9-1, Seiran 2-chome, Ohtsu-shi,
Shiga, Japan

ADDITIONAL INVENTORS FOR DECLARATION/ASSIGNMENT

Full name of additional inventor Takao MIYOSHI
Inventor's signature Takao Miyoshi 
Residence Shiga, Japan
Post Office Address c/o NEC Kansai, Ltd., 9-1, Seiran 2-chome, Ohtsu-shi,
Shiga, Japan

Date 21/08/2001Citizenship Japanese

Full name of additional inventor _____
Second Inventor's signature _____ Date _____
Residence _____ Citizenship _____
Post Office Address _____

Full name of additional inventor _____
Inventor's signature _____ Date _____
Residence _____ Citizenship _____
Post Office Address _____

Full name of additional inventor _____
Second Inventor's signature _____ Date _____
Residence _____ Citizenship _____
Post Office Address _____

Full name of additional inventor _____
Inventor's signature _____ Date _____
Residence _____ Citizenship _____
Post Office Address _____

Full name of additional inventor _____
Second Inventor's signature _____ Date _____
Residence _____ Citizenship _____
Post Office Address _____

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Inventor's signature _____ Date _____
Residence _____ Citizenship _____
Post Office Address _____

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Second Inventor's signature _____ Date _____
Residence _____ Citizenship _____
Post Office Address _____

Full name of additional inventor _____
Inventor's signature _____ Date _____
Residence _____ Citizenship _____
Post Office Address _____

Full name of additional inventor _____
Second Inventor's signature _____ Date _____
Residence _____ Citizenship _____
Post Office Address _____

THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: Gorou IKEGAMI, et al.

Filed : Concurrently herewith
For : CHIP-TYPE SEMICONDUCTOR DEVICE
....
Serial No. : Concurrently herewith

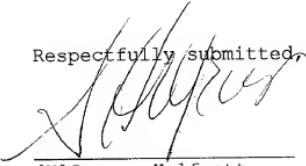
Assistant Commissioner of Patents
Washington, D.C. 20231

SUB-POWER OF ATTORNEY

S I R:

I, Samson Helfgott Reg. No. 23,072 attorney of record herein, do hereby grant a sub-power of attorney to Linda S. Chan, Reg. No. 42,400, Harris A. Wolin, Reg. No. 39,432, Brian S. Myers, Reg. No. 46,947 and Michael Markowitz, Reg. No. 30,659 to act and sign in my behalf in the above-referenced application.

Respectfully submitted,



[X] Samson Helfgott
Reg. No. 23,072
[] Aaron B. Karas
Reg. No. 18,923

HELFGOTT & KARAS, P.C.
60th FLOOR
EMPIRE STATE BUILDING
NEW YORK, NY 10118
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